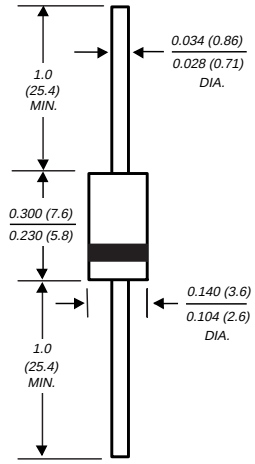
1N4383GP THRU 1N4385GP
1N4585GP AND 1N4586GP

GLASS PASSIVATED JUNCTION RECTIFIER

Reverse Voltage - *200 to 1000 Volts* ***Forward Current -*** *1.0 Ampere*

PATENTED*

DO-204AC



Dimensions in inches and (millimeters)

* *Glass-plastic encapsulation technique is covered by Patent No. 3,996,602 and brazed lead assembly by Patent No. 3,930,306*

SUPERECTIFIER®

FEATURES



- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- Glass passivated cavity-free junction
- Capable of meeting environmental standards of MIL-S-19500
- 1.0 Ampere operation at T_A=100°C with no thermal runaway
- High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: JEDEC DO-204AC molded plastic over glass body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.015 ounce, 0.4 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	*1N 4383GP*	*1N 4384GP*	*1N 4385GP*	*1N 4585GP*	*1N 4586GP*	*UNITS*
* Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	800	1000	Volts
* Maximum RMS voltage	V_{RMS}	140	280	420	560	700	Volts
* Maximum DC blocking voltage	V_{DC}	200	400	600	800	1000	Volts
* Maximum average forward rectified current 0.375" (9.5mm) lead length at T_A=100°C	$I_{(AV)}$	1.0					Amp
* Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) at T_A=100°C	I_{FSM}	50.0					Amps
Maximum instantaneous forward voltage at 1.0A	V_F	1.0					Volts
Maximum DC reverse current T_A=25°C at rated DC blocking voltage T_A=150°C	I_R	5.0 250.0					µA
* Typical reverse recovery time (NOTE 1)	t_{rr}	2.0					µs
Maximum full load reverse current full cycle average at 0.375" (9.5mm) lead length at T_A=100°C	$I_{R(AV)}$	275	250	225	200	200	µA
Typical junction capacitance (NOTE 2)	C_J	15.0					pF
Typical thermal resistance (NOTE 3)	$R_{\Theta JA}$	45.0					°C/W
* Operating junction and storage temperature range	T_J, T_{STG}	-65 to +175					°C

NOTES:
(1) Reverse recovery test conditions: I_F=0.5A, I_R=1.0A, I_{rr}=0.25A
(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts
(3) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted
* JEDEC registered values

GENERAL SEMICONDUCTOR®

RATINGS AND CHARACTERISTIC CURVES 1N4383GP THRU 1N4385GP, 1N4585GP AND 1N4586GP

FIG. 1 - FORWARD CURRENT DERATING CURVE

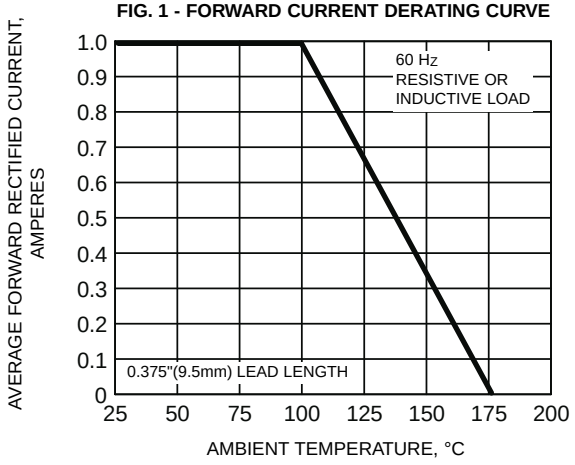


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

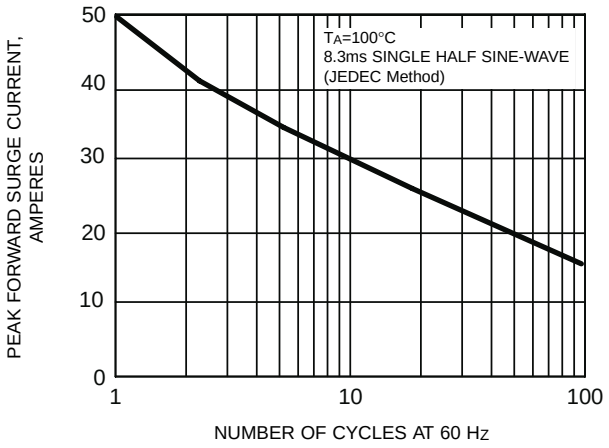


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

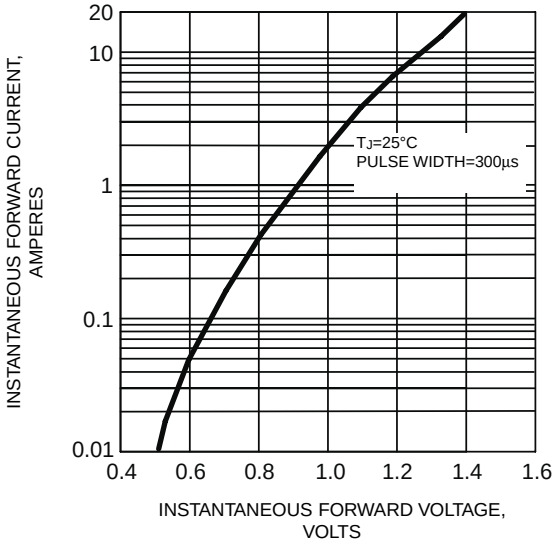


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

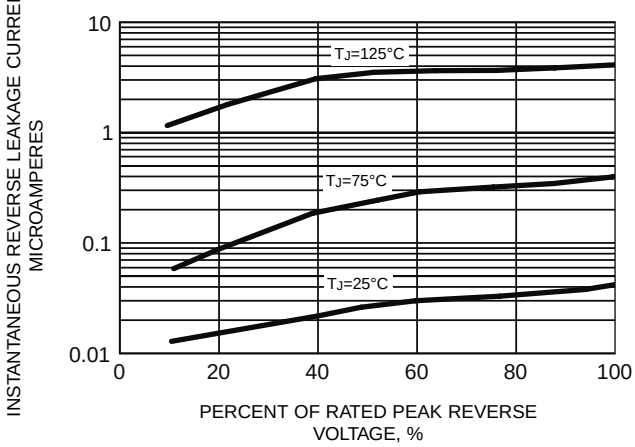


FIG. 5 - TYPICAL JUNCTION CAPACITANCE

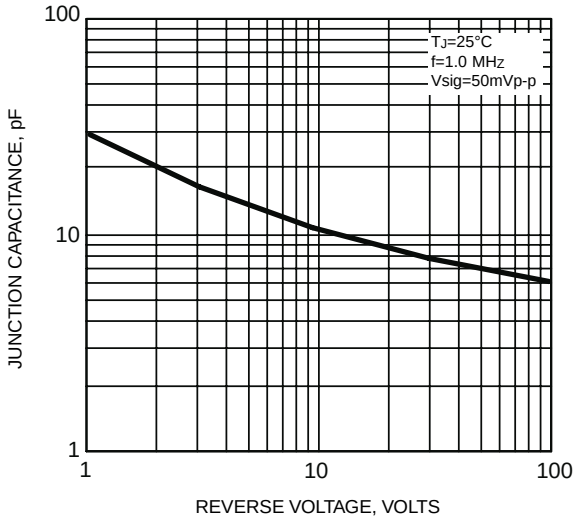
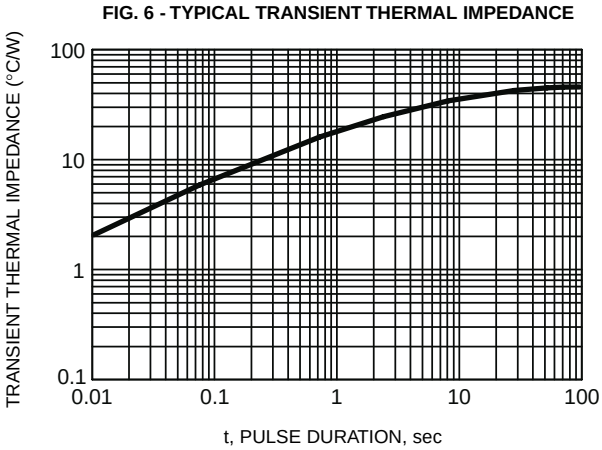


FIG. 6 - TYPICAL TRANSIENT THERMAL IMPEDANCE



GENERAL SEMICONDUCTOR®